

View Online at <https://aerobasegroup.com/nsn/5961-01-271-1762>

**Inclosure Material:**

Glass all semiconductor device diode

**Overall Length:**

0.170 inches all semiconductor device diode

**Terminal Length:**

1.000 inches all semiconductor device diode

**Overall Diameter:**

0.076 inches all semiconductor device diode

**Internal Configuration:**

Junction contact all semiconductor device diode

**Internal Junction Configuration:**

Pn all semiconductor device diode

**Component Function Relationship:**

Matched

**Component Name And Quantity:**

2 semiconductor device diode

**Mounting Method:**

Terminal all semiconductor device diode

**Field Force Effect Type:**

Electrostatic charge

**Features Provided:**

Hermetically sealed case and electrostatic sensitive

**Semiconductor Material:**

Silicon all semiconductor device diode

**Voltage Rating In Volts Per Characteristic:**

0.4 forward voltage, dc all semiconductor device diode

**Current Rating Per Characteristic:**

1.00 microamperes source cutoff current preset all semiconductor device diode

**Power Rating Per Characteristic:**

250.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode

**Maximum Operating Temperature Per Measurement Point:**

125.0 degrees celsius junction all semiconductor device diode

**Terminal Type And Quantity:**

4 uninsulated wire lead all semiconductor device diode

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fig:**

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